

74HC193-Q100; 74HCT193-Q100

Presetable synchronous 4-bit binary up/down counter

Rev. 1 — 12 July 2013

Product data sheet

1. General description

The 74HC193-Q100; 74HCT193-Q100 is a 4-bit synchronous binary up/down counter. Separate up/down clocks, CPU and CPD respectively, simplify operation. The outputs change state synchronously with the LOW-to-HIGH transition of either clock input. If the CPU clock is pulsed while CPD is held HIGH, the device counts up. If the CPD clock is pulsed while CPU is held HIGH, the device counts down. Only one clock input can be held HIGH at any time to guarantee predictable behavior. The device can be cleared at any time by the asynchronous master reset input ($\overline{\text{MR}}$). It may also be loaded in parallel by activating the asynchronous parallel load input ($\overline{\text{PL}}$). The terminal count up ($\overline{\text{TCU}}$) and terminal count down ($\overline{\text{TCD}}$) outputs are normally HIGH. When the circuit has reached the maximum count state of 15, the next HIGH-to-LOW transition of CPU causes $\overline{\text{TCU}}$ to go LOW. $\overline{\text{TCU}}$ remains LOW until CPU goes HIGH again, duplicating the count up clock. Likewise, the $\overline{\text{TCD}}$ output goes LOW when the circuit is in the zero state and the CPD goes LOW. The terminal count outputs duplicate the clock waveforms and can be used as the clock input signals to the next higher-order circuit in a multistage counter. Multistage counters are not fully synchronous, since there is a slight delay time difference added for each stage that is added. The counter may be preset by the asynchronous parallel load capability of the circuit. Information on the parallel data inputs (D_0 to D_3), is loaded into the counter. This information appears on the outputs (Q_0 to Q_3) regardless of the conditions of the clock inputs when the parallel load ($\overline{\text{PL}}$) input is LOW. A HIGH level on the master reset ($\overline{\text{MR}}$) input disables the parallel load gates. It overrides both clock inputs and sets all outputs (Q_0 to Q_3) LOW. If one of the clock inputs is LOW during and after a reset or load operation, the next LOW-to-HIGH transition of that clock is interpreted as a legitimate signal and it is counted. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Input levels:
 - ◆ For 74HC193-Q100: CMOS level
 - ◆ For 74HCT193-Q100: TTL level
- Synchronous reversible 4-bit binary counting
- Asynchronous parallel load
- Asynchronous reset
- Expandable without external logic
- Complies with JEDEC standard no. 7A



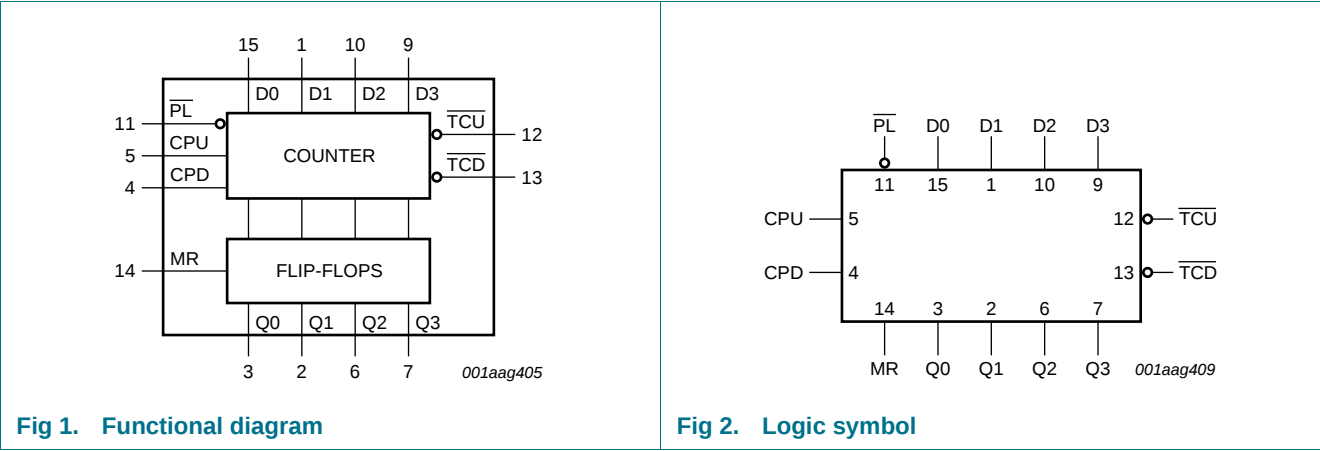
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

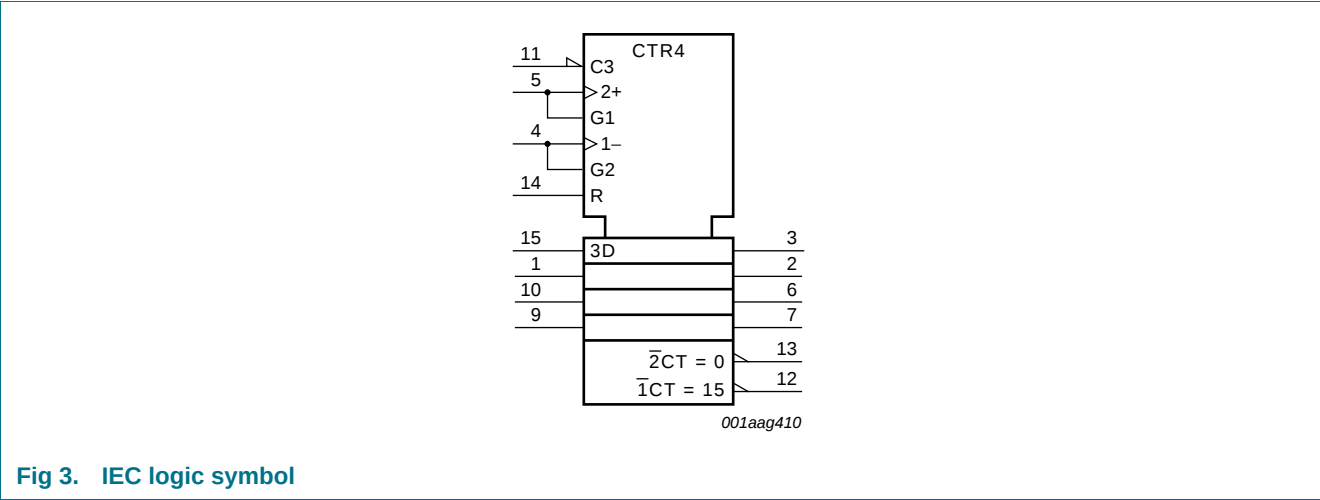
3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC193D-Q100	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC193DB-Q100	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HC193PW-Q100	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HCT193D-Q100	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT193DB-Q100	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HCT193PW-Q100	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

4. Functional diagram





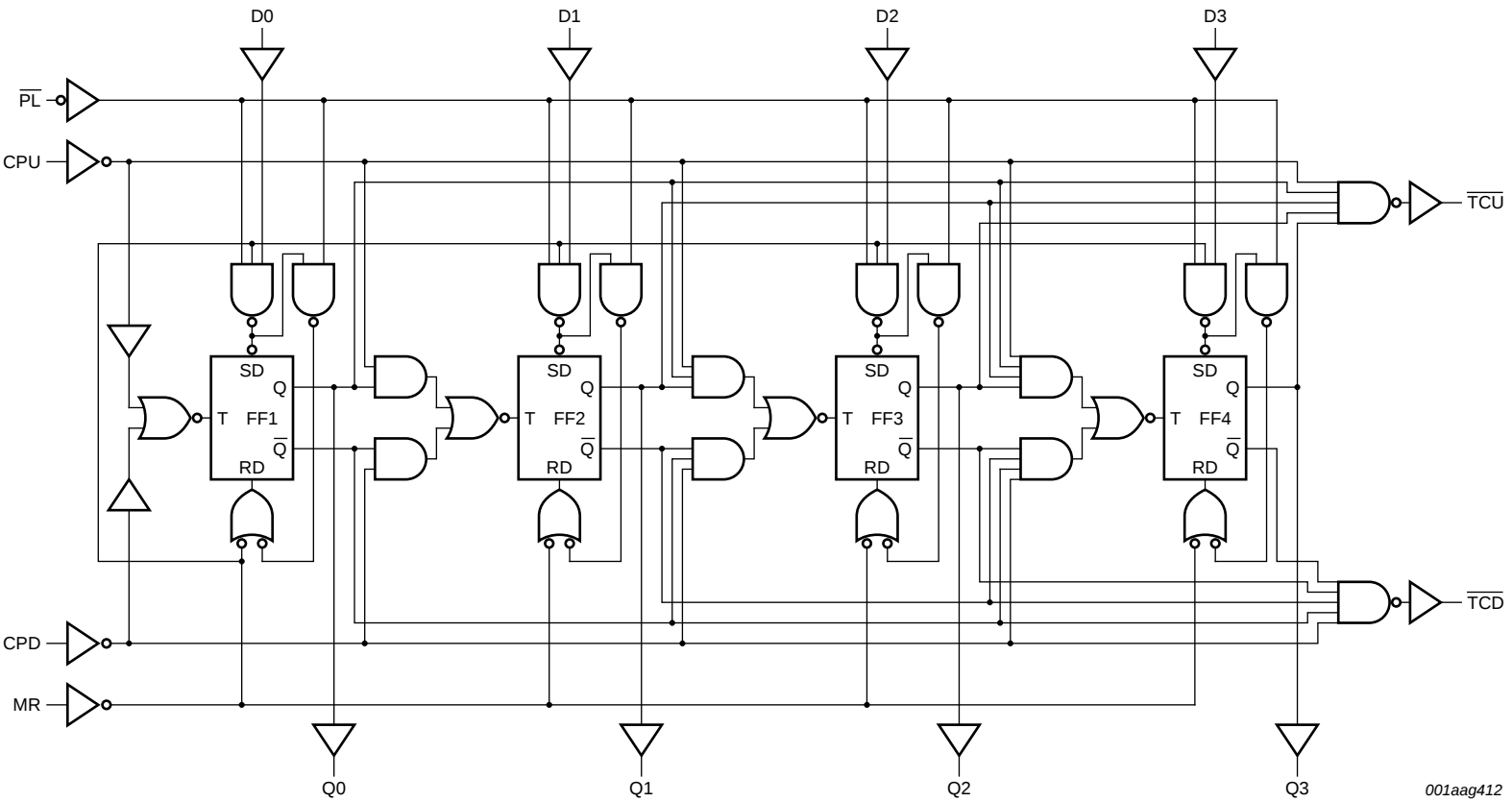


Fig 4. Logic diagram

5. Pinning information

5.1 Pinning

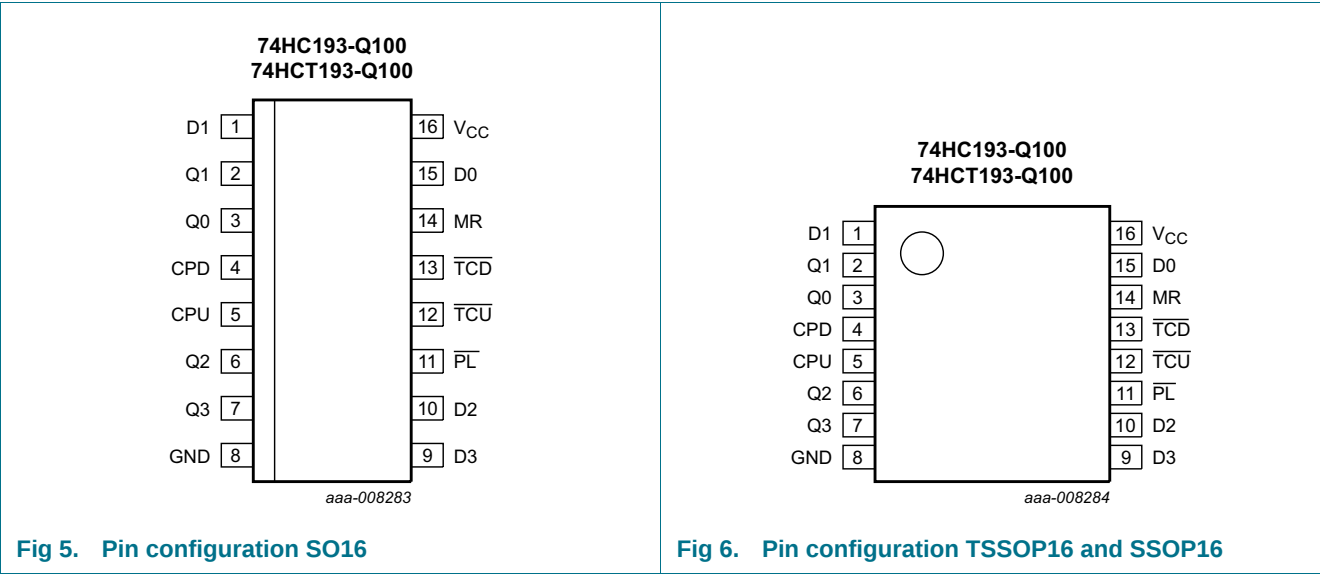


Fig 5. Pin configuration SO16

Fig 6. Pin configuration TSSOP16 and SSOP16

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
D0	15	data input 0
D1	1	data input 1
D2	10	data input 2
D3	9	data input 3
Q0	3	flip-flop output 0
Q1	2	flip-flop output 1
Q2	6	flip-flop output 2
Q3	7	flip-flop output 3
CPD	4	count down clock input ^[1]
CPU	5	count up clock input ^[1]
GND	8	ground (0 V)
PL	11	asynchronous parallel load input (active LOW)
TCU	12	terminal count up (carry) output (active LOW)
TCD	13	terminal count down (borrow) output (active LOW)
MR	14	asynchronous master reset input (active HIGH)
V _{CC}	16	supply voltage

[1] LOW-to-HIGH, edge triggered.

6. Functional description

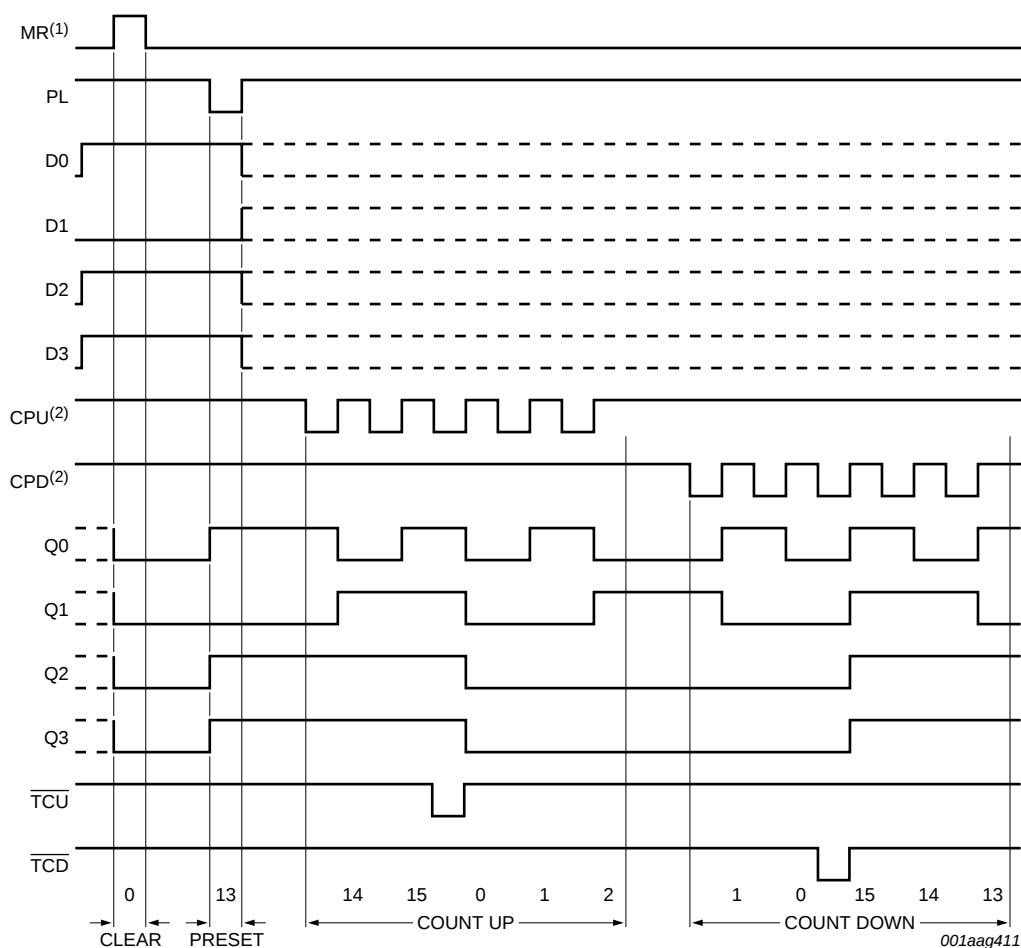
Table 3. Function table^[1]

Operating mode	Inputs								Outputs					
	MR	$\overline{\text{PL}}$	CPU	CPD	D0	D1	D2	D3	Q0	Q1	Q2	Q3	$\overline{\text{TCU}}$	$\overline{\text{TCD}}$
Reset (clear)	H	X	X	L	X	X	X	X	L	L	L	L	H	L
	H	X	X	H	X	X	X	X	L	L	L	L	H	H
Parallel load	L	L	X	L	L	L	L	L	L	L	L	L	H	L
	L	L	X	H	L	L	L	L	L	L	L	L	H	H
	L	L	L	X	H	H	H	H	H	H	H	H	L	H
	L	L	H	X	H	H	H	H	H	H	H	H	H	H
Count up	L	H	$\uparrow$	H	X	X	X	X	count up				H ^[2]	H
Count down	L	H	H	$\uparrow$	X	X	X	X	count down				H	H ^[3]

- [1] H = HIGH voltage level
 L = LOW voltage level
 X = don't care
 $\uparrow$ = LOW-to-HIGH clock transition.

- [2] $\overline{\text{TCU}}$ = CPU at terminal count up (HHHH)

- [3] $\overline{\text{TCD}}$ = CPD at terminal count down (LLLL).



- (1) Clear overrides load, data and count inputs.
- (2) When counting up, the count down clock input (CPD) must be HIGH, when counting down the count up clock input (CPU) must be HIGH.

Sequence

Clear (reset outputs to zero);

load (preset) to binary thirteen;

count up to fourteen, fifteen, terminal count up, zero, one and two;

count down to one, zero, terminal count down, fifteen, fourteen and thirteen.

Fig 7. Typical clear, load and count sequence

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
I_{IK}	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	[1] -	±20	mA
I_{OK}	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$	[1] -	±20	mA
I_O	output current	$V_O = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$	-	±25	mA
I_{CC}	supply current		-	50	mA
I_{GND}	ground current		-	-50	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation		[2] -	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO16 packages: above 70 °C the value of P_{tot} derates linearly at 8 mW/K.

For SSOP16 and TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly at 5.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
74HC193-Q100						
V _{CC}	supply voltage		2.0	5.0	6.0	V
V _I	input voltage		0	-	V _{CC}	V
V _O	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		−40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	ns/V
		V _{CC} = 4.5 V	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	ns/V
74HCT193-Q100						
V _{CC}	supply voltage		4.5	5.0	5.5	V
V _I	input voltage		0	-	V _{CC}	V
V _O	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		−40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 4.5 V	-	1.67	139	ns/V

9. Static characteristics

Table 6. Static characteristics type 74HC193-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	-	-	-	
		I _O = -20 µA; V _{CC} = 2.0 V	1.9	2.0	-	V
		I _O = -20 µA; V _{CC} = 4.5 V	4.4	4.5	-	V
		I _O = -20 µA; V _{CC} = 6.0 V	5.9	6.0	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 µA; V _{CC} = 2.0 V	-	0	0.1	V
		I _O = 20 µA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 20 µA; V _{CC} = 6.0 V	-	0	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±0.1	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	8.0	µA
C _i	input capacitance		-	3.5	-	pF
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 µA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 µA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 µA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.34	-	-	V

Table 6. Static characteristics type 74HC193-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 µA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 µA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 µA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.33	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	80	µA
T _{amb} = -40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 µA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 µA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 µA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.2	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 µA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 µA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 µA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.4	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	160	µA

Table 7. Static characteristics type 74HCT193-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V				
		I _O = -20 µA	4.4	4.5	-	V
		I _O = -4.0 mA	3.98	4.32	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V				
		I _O = 20 µA	-	0	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±0.1	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	8.0	µA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V and other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 4.5 V to 5.5 V				
		pin Dn	-	35	126	µA
		pins CPU, CPD	-	140	504	µA
		pin $\overline{\text{PL}}$	-	65	234	µA
		pin MR	-	105	378	µA
C _i	input capacitance		-	3.5	-	pF
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V				
		I _O = -20 µA	4.4	-	-	V
		I _O = -4.0 mA	3.84	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V				
		I _O = 20 µA	-	-	0.1	V
		I _O = 4.0 mA	-	-	0.33	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	80	µA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V and other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 4.5 V to 5.5 V				
		pin Dn	-	-	157.5	µA
		pins CPU, CPD	-	-	630	µA
		pin $\overline{\text{PL}}$	-	-	292.5	µA
		pin MR	-	-	472.5	µA

Table 7. Static characteristics type 74HCT193-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = -40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V				
		I _O = -20 µA	4.4	-	-	V
		I _O = -4.0 mA	3.7	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V				
		I _O = 20 µA	-	-	0.1	V
		I _O = 4.0 mA	-	-	0.4	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	160	µA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V and other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 4.5 V to 5.5 V				
		pin Dn	-	-	171.5	µA
		pins CPU, CPD	-	-	686	µA
		pin $\overline{\text{PL}}$	-	-	318.5	µA
		pin MR	-	-	514.5	µA

10. Dynamic characteristics

Table 8. Dynamic characteristics type 74HC193 -Q100

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit	
			Min	Typ	Max	Min	Max	Min	Max		
t _{pd}	propagation delay	CPU, CPD to Qn; see Figure 8	[1]	-							
		V _{CC} = 2.0 V	-	63	215	-	270	-	325	ns	
		V _{CC} = 4.5 V	-	23	43	-	54	-	65	ns	
		V _{CC} = 6.0 V	-	18	37	-	46	-	55	ns	
		CPU to TCU; see Figure 9									
		V _{CC} = 2.0 V	-	39	125	-	155	-	190	ns	
		V _{CC} = 4.5 V	-	14	25	-	31	-	38	ns	
		V _{CC} = 6.0 V	-	11	21	-	26	-	32	ns	
		CPD to TCD; see Figure 9									
		V _{CC} = 2.0 V	-	39	125	-	155	-	190	ns	
		V _{CC} = 4.5 V	-	14	25	-	31	-	38	ns	
		V _{CC} = 6.0 V	-	11	21	-	26	-	32	ns	
		PL to Qn; see Figure 10									
		V _{CC} = 2.0 V	-	69	220	-	275	-	330	ns	
		V _{CC} = 4.5 V	-	25	44	-	55	-	66	ns	
		V _{CC} = 6.0 V	-	20	37	-	47	-	56	ns	
		MR to Qn; see Figure 11									
		V _{CC} = 2.0 V	-	58	200	-	250	-	300	ns	
		V _{CC} = 4.5 V	-	21	40	-	50	-	60	ns	
		V _{CC} = 6.0 V	-	17	34		43	-	51	ns	
		Dn to Qn; see Figure 10									
		V _{CC} = 2.0 V	-	69	210	-	265	-	315	ns	
		V _{CC} = 4.5 V	-	25	42	-	53	-	63	ns	
		V _{CC} = 6.0 V	-	20	36	-	45	-	54	ns	
		PL to TCU, PL to TCD; see Figure 13									
		V _{CC} = 2.0 V	-	80	290	-	365	-	435	ns	
		V _{CC} = 4.5 V	-	29	58	-	73	-	87	ns	
		V _{CC} = 6.0 V	-	23	49	-	62	-	74	ns	
		MR to TCU, MR to TCD; see Figure 13									
		V _{CC} = 2.0 V	-	74	285	-	355	-	430	ns	
		V _{CC} = 4.5 V	-	27	57	-	71	-	86	ns	
		V _{CC} = 6.0 V	-	22	48	-	60	-	73	ns	

Table 8. Dynamic characteristics type 74HC193 ...continued-Q100

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{pd}	propagation delay	Dn to $\overline{TCU}$, Dn to TCD; see Figure 13								
		$V_{CC} = 2.0\text{ V}$	-	80	290	-	365	-	435	ns
		$V_{CC} = 4.5\text{ V}$	-	29	58	-	73	-	87	ns
		$V_{CC} = 6.0\text{ V}$	-	23	49	-	62	-	74	ns
t_{THL}	HIGH to LOW output transition time	see Figure 11								
		$V_{CC} = 2.0\text{ V}$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5\text{ V}$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0\text{ V}$	-	6	13	-	16	-	19	ns
t_{TLH}	LOW to HIGH output transition time	see Figure 11								
		$V_{CC} = 2.0\text{ V}$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5\text{ V}$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0\text{ V}$	-	6	13	-	16	-	19	ns
t_w	pulse width	CPU, CPD (HIGH or LOW); see Figure 8								
		$V_{CC} = 2.0\text{ V}$	100	22	-	125	-	150	-	ns
		$V_{CC} = 4.5\text{ V}$	20	8	-	25	-	30	-	ns
		$V_{CC} = 6.0\text{ V}$	17	6	-	21	-	26	-	ns
		MR (HIGH); see Figure 11								
		$V_{CC} = 2.0\text{ V}$	100	25	-	125	-	150	-	ns
		$V_{CC} = 4.5\text{ V}$	20	9	-	25	-	30	-	ns
		$V_{CC} = 6.0\text{ V}$	17	7	-	21	-	26	-	ns
		$\overline{PL}$ (LOW); see Figure 10								
		$V_{CC} = 2.0\text{ V}$	100	19	-	125	-	150	-	ns
		$V_{CC} = 4.5\text{ V}$	20	7	-	25	-	30	-	ns
		$V_{CC} = 6.0\text{ V}$	17	6	-	21	-	26	-	ns
		PL to CPU, CPD; see Figure 10								
		$V_{CC} = 2.0\text{ V}$	50	8	-	65	-	75	-	ns
		$V_{CC} = 4.5\text{ V}$	10	3	-	13	-	15	-	ns
		$V_{CC} = 6.0\text{ V}$	9	2	-	11	-	13	-	ns
t_{rec}	recovery time	MR to CPU, CPD; see Figure 11								
		$V_{CC} = 2.0\text{ V}$	50	0	-	65	-	75	-	ns
		$V_{CC} = 4.5\text{ V}$	10	0	-	13	-	15	-	ns
		$V_{CC} = 6.0\text{ V}$	9	0	-	11	-	13	-	ns

Table 8. Dynamic characteristics type 74HC193 ...continued-Q100

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{su}	set-up time	Dn to $\overline{PL}$; see Figure 12 ; note: CPU = CPD = HIGH								
		$V_{CC} = 2.0\text{ V}$	80	22	-	100	-	120	-	ns
		$V_{CC} = 4.5\text{ V}$	16	8	-	20	-	24	-	ns
		$V_{CC} = 6.0\text{ V}$	14	6	-	17	-	20	-	ns
t_h	hold time	Dn to $\overline{PL}$; see Figure 12								
		$V_{CC} = 2.0\text{ V}$	0	-14	-	0	-	0	-	ns
		$V_{CC} = 4.5\text{ V}$	0	-5	-	0	-	0	-	ns
		$V_{CC} = 6.0\text{ V}$	0	-4	-	0	-	0	-	ns
		CPU to CPD, CPD to CPU; see Figure 14								
		$V_{CC} = 2.0\text{ V}$	80	22	-	100	-	120	-	ns
		$V_{CC} = 4.5\text{ V}$	16	8	-	20	-	24	-	ns
		$V_{CC} = 6.0\text{ V}$	8	6	-	17	-	20	-	ns
f_{max}	maximum frequency	CPU, CPD; see Figure 8								
		$V_{CC} = 2.0\text{ V}$	4.0	13.5	-	3.2	-	2.6	-	MHz
		$V_{CC} = 4.5\text{ V}$	20	41	-	16	-	13	-	MHz
		$V_{CC} = 6.0\text{ V}$	24	49	-	19	-	15	-	MHz
C_{PD}	power dissipation capacitance	$V_I = \text{GND to } V_{CC}$; [2] $V_{CC} = 5\text{ V}$; $f_i = 1\text{ MHz}$	-	24	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Table 9. Dynamic characteristics type 74HCT193 -Q100

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{pd}	propagation delay	CPU, CPD to Qn; see Figure 8 ^[1]								
		$V_{CC} = 4.5\text{ V}$	-	23	43	-	54	-	65	ns
		CPU to $\overline{TCU}$; see Figure 9								
		$V_{CC} = 4.5\text{ V}$	-	15	27	-	34	-	41	ns
		CPD to $\overline{TCD}$; see Figure 9								
		$V_{CC} = 4.5\text{ V}$	-	15	27	-	34	-	41	ns
		PL to Qn; see Figure 10								
		$V_{CC} = 4.5\text{ V}$	-	26	46	-	58	-	69	ns
		MR to Qn; see Figure 11								
		$V_{CC} = 4.5\text{ V}$	-	22	40	-	50	-	60	ns
		Dn to Qn; see Figure 10								
		$V_{CC} = 4.5\text{ V}$	-	27	46	-	58	-	69	ns
t_{THL}	HIGH to LOW output transition time	$\overline{PL}$ to $\overline{TCU}$, $\overline{PL}$ to $\overline{TCD}$; see Figure 13								
		$V_{CC} = 4.5\text{ V}$	-	31	55	-	69	-	83	ns
		MR to $\overline{TCU}$, MR to $\overline{TCD}$; see Figure 13								
t_{TLH}	LOW to HIGH output transition time	$V_{CC} = 4.5\text{ V}$	-	29	55	-	69	-	83	ns
		Dn to $\overline{TCU}$, Dn to $\overline{TCD}$; see Figure 13								
		$V_{CC} = 4.5\text{ V}$	-	32	58	-	73	-	87	ns
t_w	pulse width	see Figure 11								
		$V_{CC} = 4.5\text{ V}$	-	7	15	-	19	-	22	ns
		see Figure 11								
		$V_{CC} = 4.5\text{ V}$	-	7	15	-	19	-	22	ns
		CPU, CPD (HIGH or LOW); see Figure 8								
t_w	pulse width	MR (HIGH); see Figure 11								
		$V_{CC} = 4.5\text{ V}$	25	11	-	31	-	38	-	ns
		PL (LOW); see Figure 10								
		$V_{CC} = 4.5\text{ V}$	20	7	-	25	-	30	-	ns
		$V_{CC} = 4.5\text{ V}$	20	8	-	25	-	30	-	ns

Table 9. Dynamic characteristics type 74HCT193 ...continued-Q100

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{rec}	recovery time	$\overline{\text{PL}}$ to CPU, CPD; see Figure 10								
		$V_{\text{CC}} = 4.5 \text{ V}$	10	2	-	13	-	15	-	ns
		MR to CPU, CPD; see Figure 11								
		$V_{\text{CC}} = 4.5 \text{ V}$	10	0	-	13	-	15	-	ns
t_{su}	set-up time	Dn to $\overline{\text{PL}}$; see Figure 12 ; note: CPU = CPD = HIGH								
		$V_{\text{CC}} = 4.5 \text{ V}$	16	8	-	20	-	24	-	ns
t_{h}	hold time	Dn to $\overline{\text{PL}}$; see Figure 12								
		$V_{\text{CC}} = 4.5 \text{ V}$	0	-6	-	0	-	0	-	ns
		CPU to CPD, CPD to CPU; see Figure 14								
		$V_{\text{CC}} = 4.5 \text{ V}$	16	7	-	20	-	24	-	ns
f_{max}	maximum frequency	CPU, CPD; see Figure 8								
		$V_{\text{CC}} = 4.5 \text{ V}$	20	43	-	16	-	13	-	MHz
C_{PD}	power dissipation capacitance	$V_{\text{I}} = \text{GND to } V_{\text{CC}} - [2]$ 1.5 V; $V_{\text{CC}} = 5 \text{ V}$; $f_{\text{i}} = 1 \text{ MHz}$	-	26	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] C_{PD} is used to determine the dynamic power dissipation (P_{D} in μW):

$$P_{\text{D}} = C_{\text{PD}} \times V_{\text{CC}}^2 \times f_{\text{i}} \times N + \sum (C_{\text{L}} \times V_{\text{CC}}^2 \times f_{\text{o}}) \text{ where:}$$

f_{i} = input frequency in MHz;

f_{o} = output frequency in MHz;

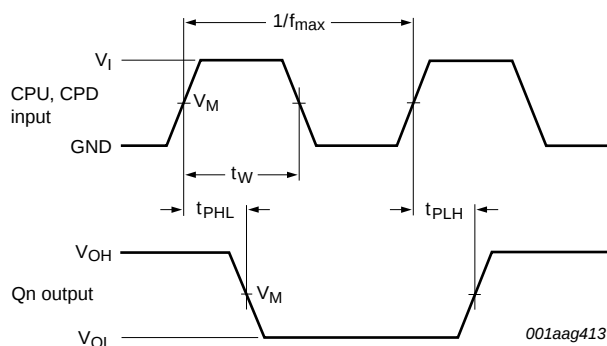
C_{L} = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum (C_{\text{L}} \times V_{\text{CC}}^2 \times f_{\text{o}}) = \text{sum of outputs.}$

11. Waveforms

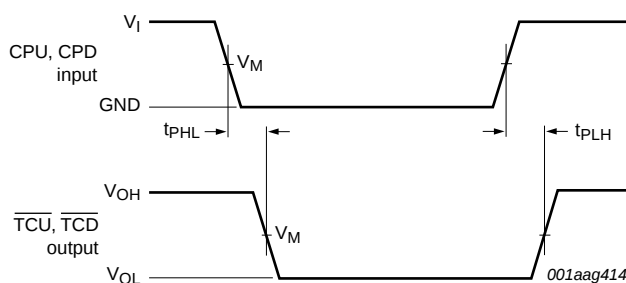


Measurement points are given in [Table 10](#).

t_{PLH} and t_{PHL} are the same as t_{pd} .

Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8. The clock (CPU, CPD) to output (Qn) propagation delays, the clock pulse width, and the maximum clock pulse frequency

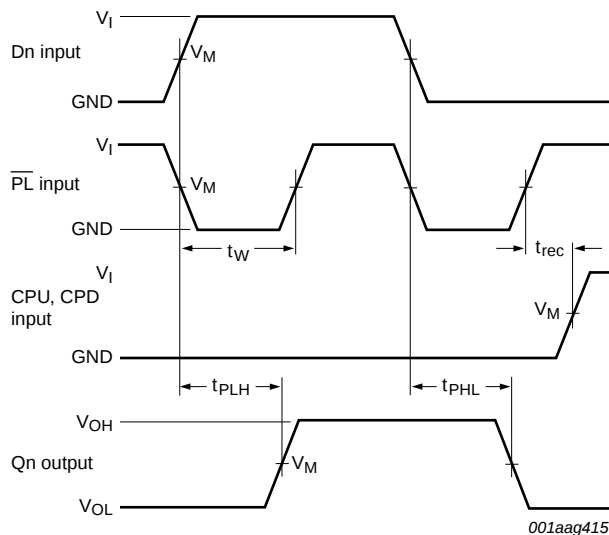


Measurement points are given in [Table 10](#).

t_{PLH} and t_{PHL} are the same as t_{pd} .

Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 9. The clock (CPU, CPD) to terminal count output ($\overline{TCU}$, $\overline{TCD}$) propagation delays



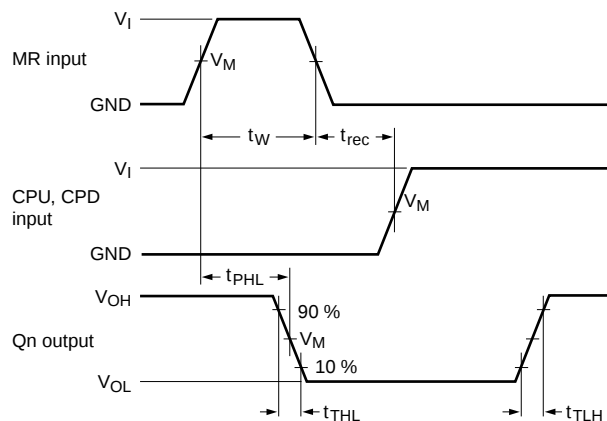
001aag415

Measurement points are given in [Table 10](#).

t_{PLH} and t_{PHL} are the same as t_{pd} .

Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 10. The parallel load input (PL) and data (Dn) to Qn output propagation delays and PL removal time to clock input (CPU, CPD)



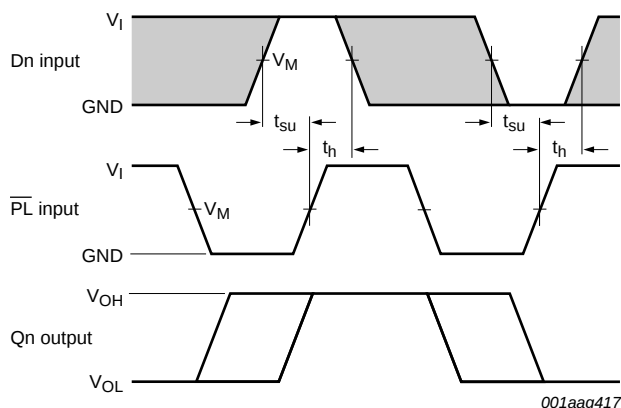
001aag416

Measurement points are given in [Table 10](#).

t_{PLH} and t_{PHL} are the same as t_{pd} .

Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 11. The master reset input (MR) pulse width, MR to Qn propagation delays, MR to CPU, CPD removal time and output transition times

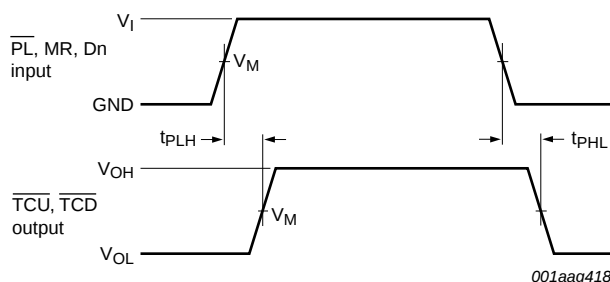


The shaded areas indicate when the input is permitted to change for predictable output performance.

Measurement points are given in [Table 10](#).

Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 12. The data input (Dn) to parallel load input ($\overline{PL}$) set-up and hold times

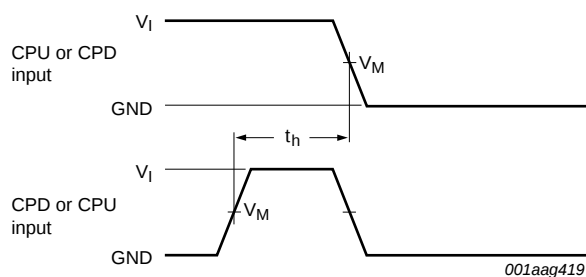


Measurement points are given in [Table 10](#).

t_{PLH} and t_{PHL} are the same as t_{pd} .

Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 13. The data input (Dn), parallel load input ($\overline{PL}$) and the master reset input (MR) to the terminal count outputs (TCU, TCD) propagation delays



Measurement points are given in [Table 10](#).

Fig 14. The CPU to CPD or CPD to CPU hold times

Table 10. Measurement points

Type	Input		Output
	V_M	V_I	V_M
74HC193-Q100	$0.5 \times V_{CC}$	GND to V_{CC}	$0.5 \times V_{CC}$
74HCT193-Q100	1.3 V	GND to 3 V	1.3 V

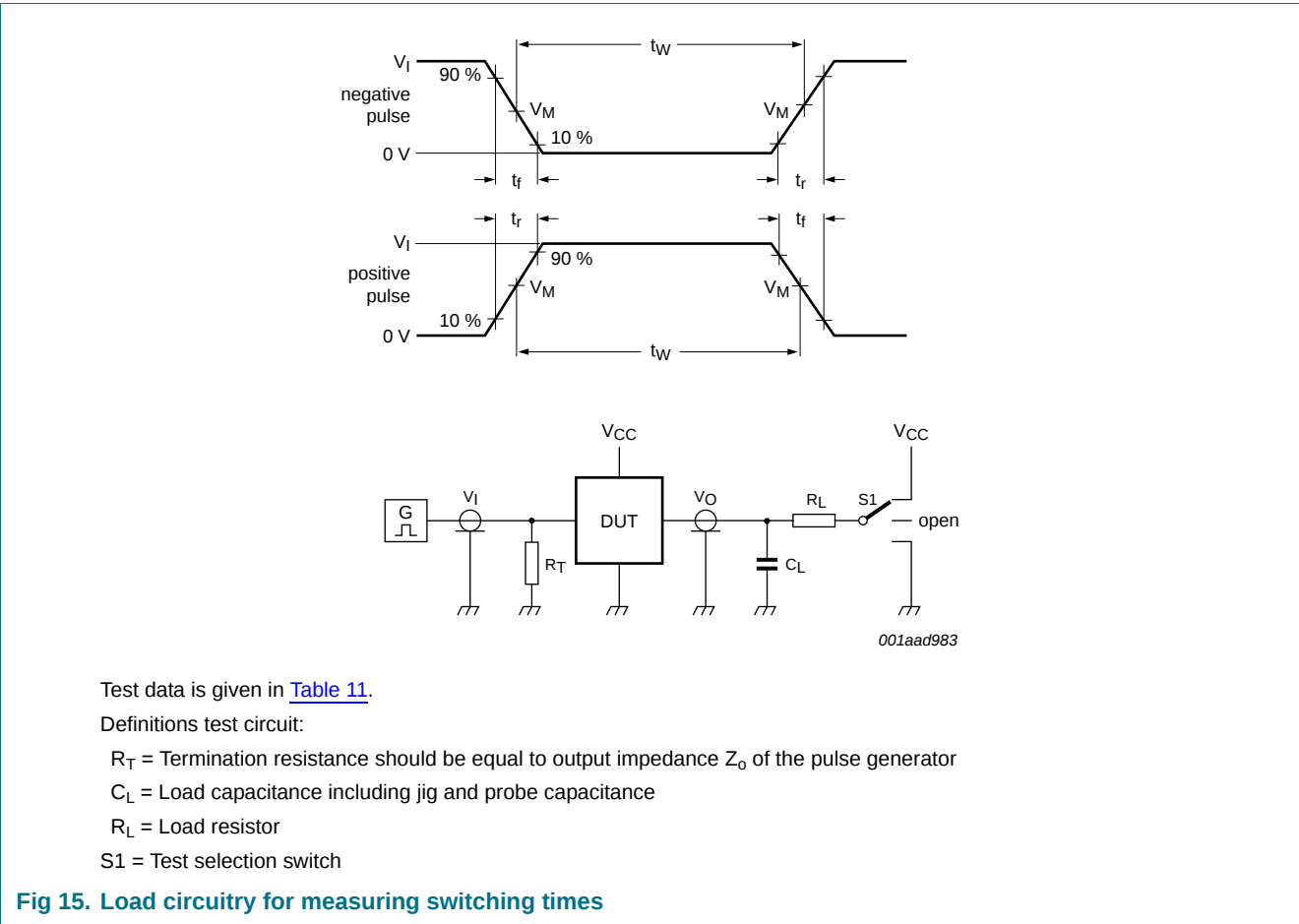


Table 11. Test data

Type	Input		Load		S1 position
	V_I	t_r, t_f	C_L	R_L	t_{PHL}, t_{PLH}
74HC193-Q100	V_{CC}	6 ns	15 pF, 50 pF	1 k Ω	open
74HCT193-Q100	3 V	6 ns	15 pF, 50 pF	1 k Ω	open

12. Application information

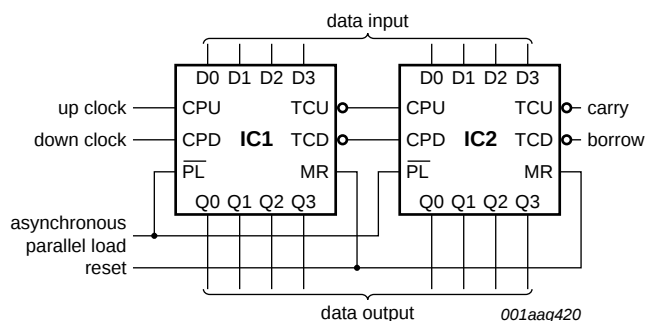
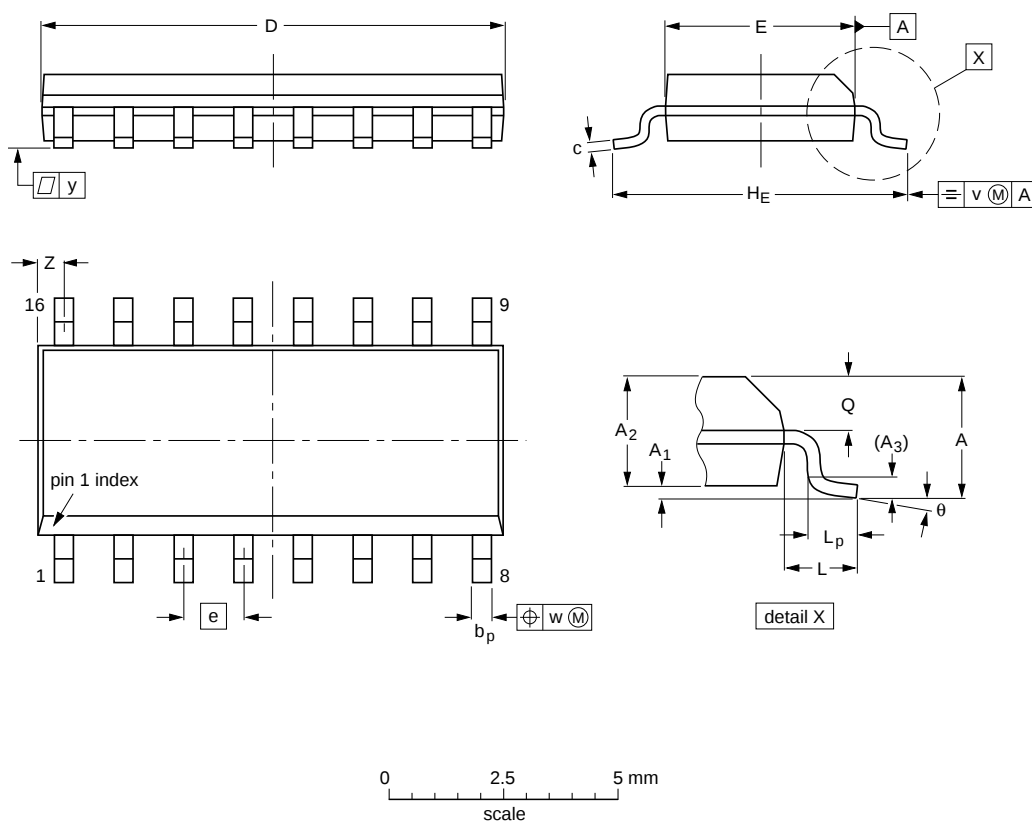


Fig 16. Application for cascaded up/down counter with parallel load

13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig 17. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

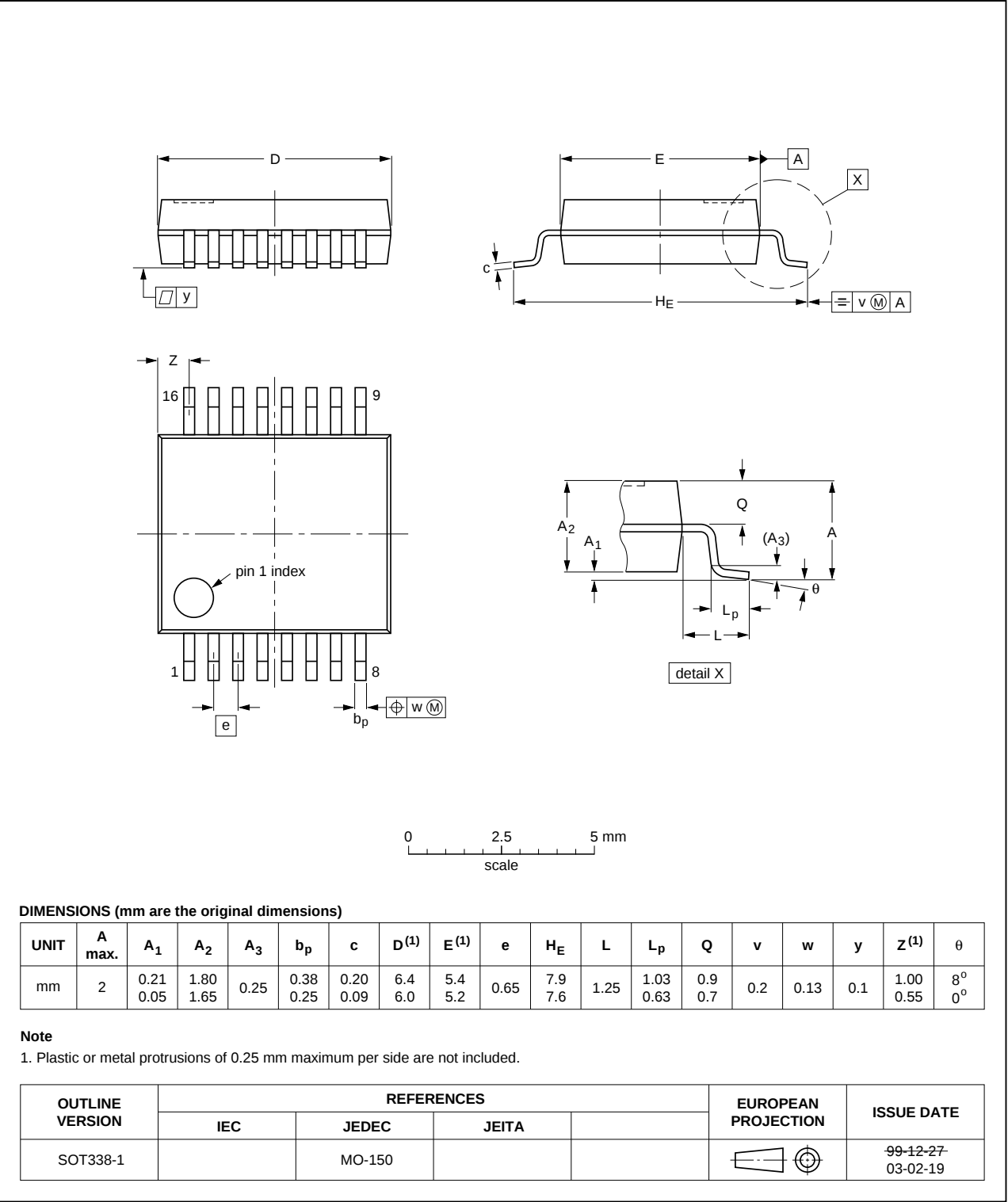
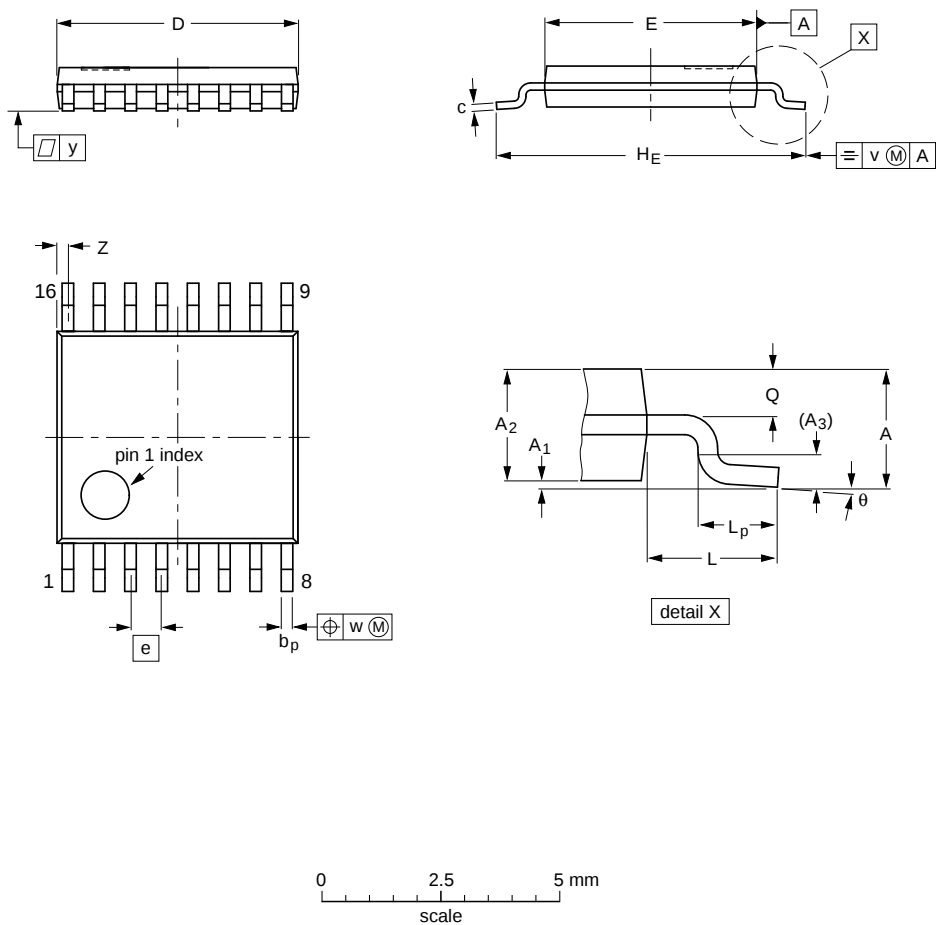


Fig 18. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT403-1		MO-153				99-12-27 03-02-18

Fig 19. Package outline SOT403-1 (TSSOP16)

14. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model
MIL	Military
TTL	Transistor-Transistor Logic

15. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT193_Q100 v.1	20130712	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

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